Data Sheet | October 29, 2007 | FN7389.8

600MHz Current Feedback Amplifiers with Enable

The EL5164, EL5165, and EL5364 are current feedback amplifiers with a very high bandwidth of 600MHz. This makes these amplifiers ideal for today's high speed video and monitor applications.

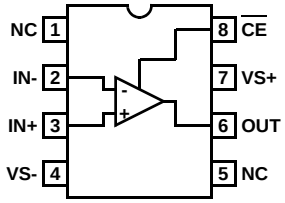
With a supply current of just 5mA and the ability to run from a single supply voltage from 5V to 12V, the amplifiers are also ideal for hand held, portable or battery-powered equipment.

The EL5164 also incorporates an enable and disable function to reduce the supply current to 100µA typical per amplifier. Allowing the $\overline{CE}$ pin to float or applying a low logic level will enable the amplifier.

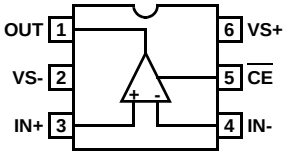
The EL5165 is offered in the 5 Ld SOT-23 and 5 Ld SC-70 packages, EL5164 is available in the 6 Ld SOT-23 and the industry-standard 8 Ld SOIC packages, and the EL5364 in a 16 Ld SOIC and 16 Ld QSOP packages. All operate over the industrial temperature range of -40°C to +85°C.

Pinouts

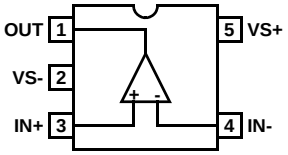
EL5164
(8 LD SOIC)
TOP VIEW



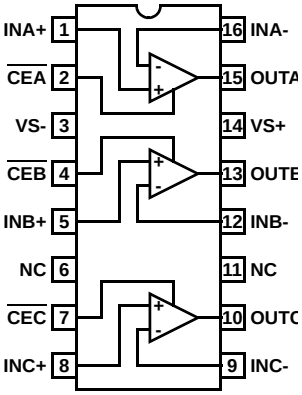
EL5164
(6 LD SOT-23)
TOP VIEW



EL5165
(5 LD SOT-23, SC-70)
TOP VIEW



EL5364
(16 LD SOIC, QSOP)
TOP VIEW



Features

- 600MHz -3dB bandwidth
- 4700V/µs slew rate
- 5mA supply current
- Single and dual supply operation, from 5V to 12V supply span
- Fast enable/disable (EL5164 and EL5364 only)
- Available in SOT-23 packages
- Dual (EL5264 and EL5265) and triple (EL5362 and EL5363) also available
- High speed, 1GHz product available (EL5166 and EL5167)
- 300MHz product available (EL5162 family)
- Pb-Free available (RoHS compliant)

Applications

- Video amplifiers
- Cable drivers
- RGB amplifiers
- Test equipment
- Instrumentation
- Current to voltage converters

CAUTION: These devices are sensitive to electrostatic discharge; follow proper IC Handling Procedures.
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Ordering Information

PART NUMBER	PART MARKING	PACKAGE	PKG. DWG. #
EL5164IS	5164IS	8 Ld SOIC (150 mil)	MDP0027
EL5164IS-T7*	5164IS	8 Ld SOIC (150 mil)	MDP0027
EL5164IS-T13*	5164IS	8 Ld SOIC (150 mil)	MDP0027
EL5164ISZ (Note)	5164ISZ	8 Ld SOIC (150 mil) (Pb-free)	MDP0027
EL5164ISZ-T7* (Note)	5164ISZ	8 Ld SOIC (150 mil) (Pb-free)	MDP0027
EL5164ISZ-T13* (Note)	5164ISZ	8 Ld SOIC (150 mil) (Pb-free)	MDP0027
EL5164IW-T7*	i	6 Ld SOT-23	MDP0038
EL5164IW-T7A*	i	6 Ld SOT-23	MDP0038
EL5164IWZ-T7* (Note)	BAMA	6 Ld SOT-23 (Pb-free)	MDP0038
EL5164IWZ-T7A* (Note)	BAMA	6 Ld SOT-23 (Pb-free)	MDP0038
EL5165IC-T7*	F	5 Ld SC-70 (1.25mm)	P5.049
EL5165IC-T7A*	F	5 Ld SC-70 (1.25mm)	P5.049
EL5165IW-T7*	b	5 Ld SOT-23	MDP0038
EL5165IW-T7A*	b	5 Ld SOT-23	MDP0038
EL5165IWZ-T7* (Note)	BANA	5 Ld SOT-23 (Pb-free)	MDP0038
EL5165IWZ-T7A* (Note)	BANA	5 Ld SOT-23 (Pb-free)	MDP0038
EL5364IS	EL5364IS	16 Ld SOIC (150 mil)	MDP0027
EL5364IS-T7*	EL5364IS	16 Ld SOIC (150 mil)	MDP0027
EL5364IS-T13*	EL5364IS	16 Ld SOIC (150 mil)	MDP0027
EL5364ISZ (Note)	EL5364ISZ	16 Ld SOIC (150 mil) (Pb-free)	MDP0027
EL5364ISZ-T7* (Note)	EL5364ISZ	16 Ld SOIC (150 mil) (Pb-free)	MDP0027
EL5364ISZ-T13* (Note)	EL5364ISZ	16 Ld SOIC (150 mil) (Pb-free)	MDP0027
EL5364IU	5364IU	16 Ld QSOP (150 mil)	MDP0040
EL5364IU-T7*	5364IU	16 Ld QSOP (150 mil)	MDP0040
EL5364IU-T13*	5364IU	16 Ld QSOP (150 mil)	MDP0040
EL5364IUZ (Note)	5364IUZ	16 Ld QSOP (150 mil) (Pb-free)	MDP0040
EL5364IUZ-T7* (Note)	5364IUZ	16 Ld QSOP (150 mil) (Pb-free)	MDP0040
EL5364IUZ-T13* (Note)	5364IUZ	16 Ld QSOP (150 mil) (Pb-free)	MDP0040
EL5364IUZA (Note)	5364IUZ	16 Ld QSOP (150 mil) (Pb-free)	MDP0040
EL5364IUZA-T7* (Note)	5364IUZ	16 Ld QSOP (150 mil) (Pb-free)	MDP0040
EL5364IUZA-T13* (Note)	5364IUZ	16 Ld QSOP (150 mil) (Pb-free)	MDP0040

*Please refer to TB347 for details on reel specifications.

NOTE: These Intersil Pb-free plastic packaged products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate PLUS ANNEAL - e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Absolute Maximum Ratings (T_A = +25°C)

Supply Voltage between V_S+ and V_S- 13.2V
Maximum Continuous Output Current 50mA
Pin Voltages . . . . . V_S- -0.5V to V_S+ +0.5V
Supply Slewrate between V_S+ and V_S- . . . . . 1V/µs (Max)
$V_{IN-DIFF}$ (V_{IN}+ - V_{IN}-) (When Disabled) . . . . . ±2V (Max)

Thermal Information

Power Dissipation . . . . . See Curves
Storage Temperature . . . . . -65°C to +150°C
Ambient Operating Temperature . . . . . -40°C to +85°C
Operating Junction Temperature . . . . . +125°C
Pb-free reflow profile . . . . . .see link below
http://www.intersil.com/pbfree/Pb-FreeReflow.asp

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

Electrical Specifications

V_S+ = +5V, V_S- = -5V, R_F = 750Ω for A_V = 1, R_F = 375Ω for A_V = 2, R_L = 150Ω, V_{ENABLE} = V_S+ - 1V, T_A = +25°C unless otherwise specified.

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 2)	TYP	MAX (Note 2)	UNIT
AC PERFORMANCE						
BW	-3dB Bandwidth	A_V = +1, R_L = 500Ω, R_F = 510Ω		600		MHz
		A_V = +2, R_L = 150Ω, R_F = 412Ω		450		MHz
BW1	0.1dB Bandwidth	A_V = +2, R_L = 150Ω, R_F = 412Ω		50		MHz
SR	Slew Rate	V_{OUT} = -3V to +3V, A_V = +2, R_L = 100Ω (EL5164, EL5165)	3500	4700	7000	V/µs
		V_{OUT} = -3V to +3V, A_V = +2, R_L = 100Ω (EL5364)	3000	4200	6000	V/µs
t_S	0.1% Settling Time	V_{OUT} = -2.5V to +2.5V, A_V = +2, R_F = R_G = 1kΩ		15		ns
e_N	Input Voltage Noise	f = 1MHz		2.1		nV/√Hz
i_N-	IN- Input Current Noise	f = 1MHz		13		pA/√Hz
i_N+	IN+ Input Current Noise	f = 1MHz		13		pA/√Hz
HD2		5MHz, 2.5V_{P-P}		-81		dBc
HD3		5MHz, 2.5V_{P-P}		-74		dBc
dG	Differential Gain Error (Note 1)	A_V = +2		0.01		%
dP	Differential Phase Error (Note 1)	A_V = +2		0.01		°
DC PERFORMANCE						
V_{OS}	Offset Voltage		-5	1.5	+5	mV
T_CV_{OS}	Input Offset Voltage Temperature Coefficient	Measured from T_{MIN} to T_{MAX}		6		µV/°C
R_{OL}	Transimpedance		1.1	3		MΩ
INPUT CHARACTERISTICS						
CMIR	Common Mode Input Range	Guaranteed by CMRR test	±3	±3.3		V
CMRR	Common Mode Rejection Ratio	V_{IN} = ±3V	50	62	75	dB
-ICMR	- Input Current Common Mode Rejection		-1	0.1	+1	µA/V
$+I_{IN}$	+ Input Current		-10	2	+10	µA
$-I_{IN}$	- Input Current		-10	2	+10	µA
R_{IN}	Input Resistance	+ Input	300	650	1200	kΩ
C_{IN}	Input Capacitance			1		pF

Electrical Specifications $V_S+ = +5V$, $V_S- = -5V$, $R_F = 750\Omega$ for $A_V = 1$, $R_F = 375\Omega$ for $A_V = 2$, $R_L = 150\Omega$, $V_{ENABLE} = V_S+ - 1V$, $T_A = +25°C$ unless otherwise specified. **(Continued)**

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 2)	TYP	MAX (Note 2)	UNIT
OUTPUT CHARACTERISTICS						
V_O	Output Voltage Swing	$R_L = 150\Omega$ to GND	±3.6	±3.8	±4.0	V
		$R_L = 1k\Omega$ to GND	±3.9	±4.1	±4.2	V
I_{OUT}	Output Current	$R_L = 10\Omega$ to GND	100	140	190	mA
SUPPLY						
I_{SON}	Supply Current - Enabled	No load, $V_{IN} = 0V$	3.2	3.5	4.2	mA
I_{SOFF+}	Supply Current - Disabled, per Amplifier		0		+25	µA
I_{SOFF-}	Supply Current - Disabled, per Amplifier	No load, $V_{IN} = 0V$	-25	-14	0	µA
PSRR	Power Supply Rejection Ratio	DC, $V_S = ±4.75V$ to ±5.25V	65	79		dB
-IPSR	- Input Current Power Supply Rejection	DC, $V_S = ±4.75V$ to ±5.25V	-1	0.1	+1	µA/V
ENABLE (EL5164 ONLY)						
t_{EN}	Enable Time			200		ns
t_{DIS}	Disable Time			800		ns
I_{IHCE}	$\overline{CE}$ Pin Input High Current	$\overline{CE} = V_S+$	1	10	+25	µA
I_{ILCE}	$\overline{CE}$ Pin Input Low Current	$\overline{CE} = (V_S+) -5V$	-1	0	+1	µA
V_{IHCE}	$\overline{CE}$ Input High Voltage for Power-down		$V_S+ - 1$			V
V_{ILCE}	$\overline{CE}$ Input Low Voltage for Power-down				$V_S+ - 3$	V

NOTE:

1. Standard NTSC test, AC signal amplitude = $286mV_{P-P}$, f = 3.58MHz
2. Parts are 100% tested at +25°C. Over-temperature limits established by characterization and are not production tested.

Typical Performance Curves

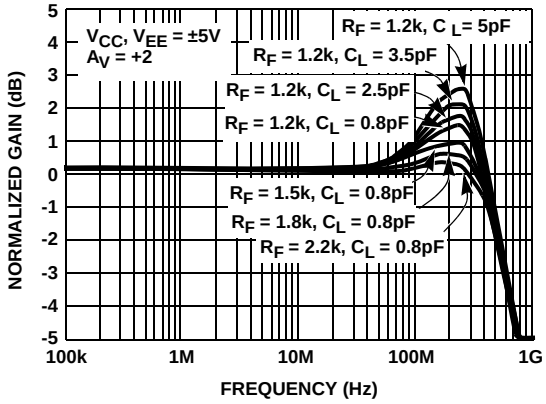


FIGURE 1. FREQUENCY RESPONSE FOR VARIOUS R_F AND C_L

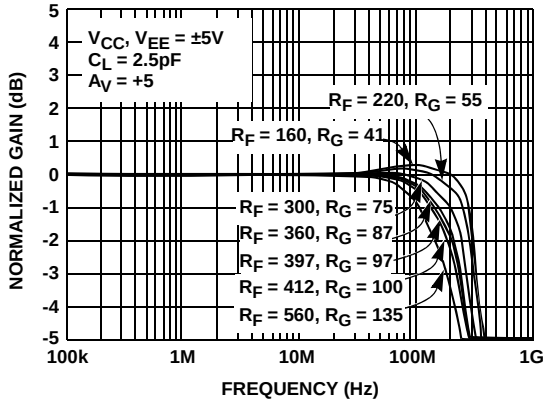


FIGURE 2. FREQUENCY RESPONSE FOR VARIOUS R_F

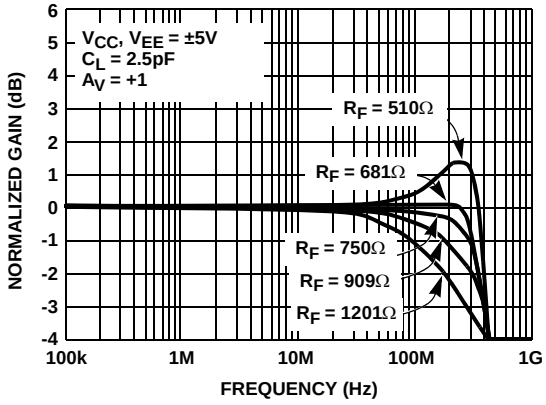


FIGURE 3. FREQUENCY RESPONSE FOR VARIOUS R_F

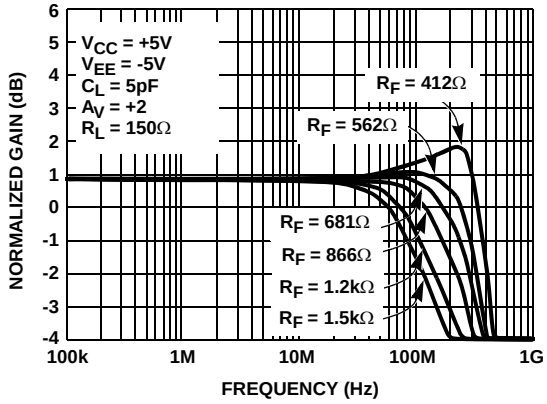


FIGURE 4. FREQUENCY RESPONSE FOR VARIOUS R_F

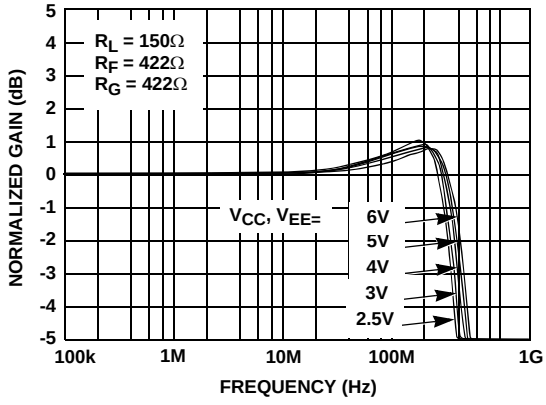


FIGURE 5. FREQUENCY RESPONSE FOR VARIOUS POWER SUPPLY VOLTAGES

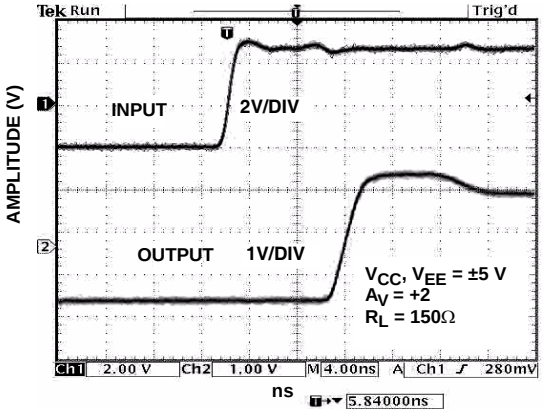


FIGURE 6. RISE TIME (ns)

Typical Performance Curves (Continued)

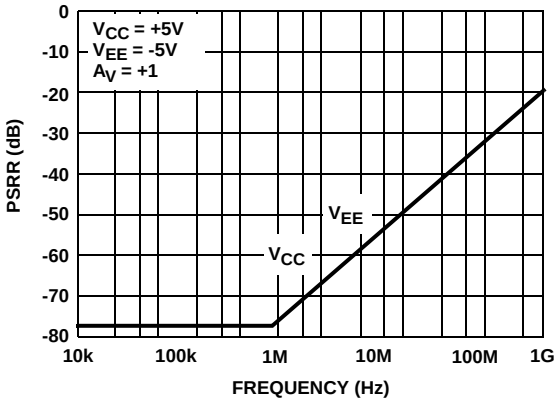


FIGURE 7. PSRR

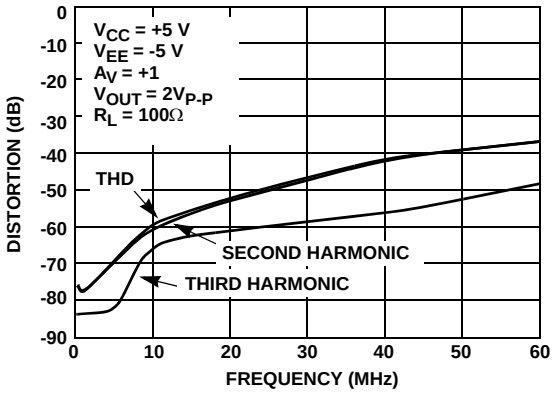


FIGURE 8. DISTORTION vs FREQUENCY (A_V = +1)

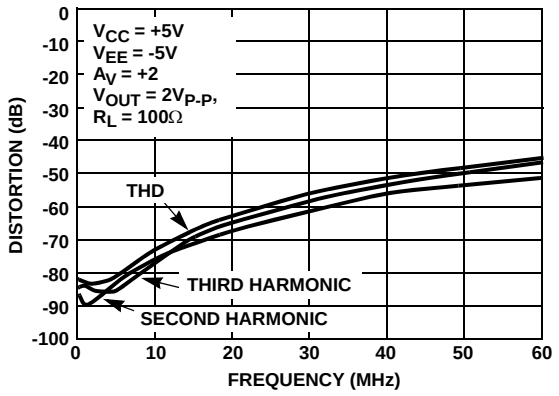


FIGURE 9. DISTORTION vs FREQUENCY (A_V = +2)

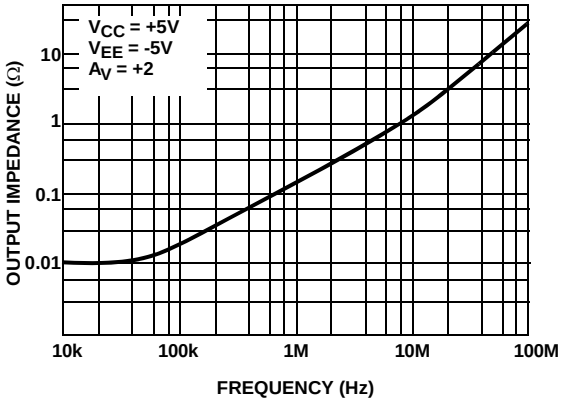


FIGURE 10. OUTPUT IMPEDANCE

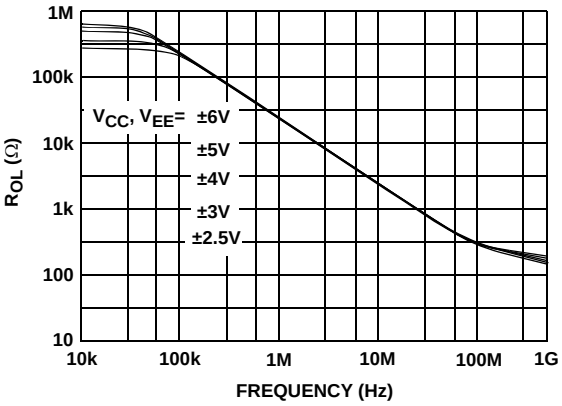


FIGURE 11. R_{OL} FOR VARIOUS V_{CC}, V_{EE}

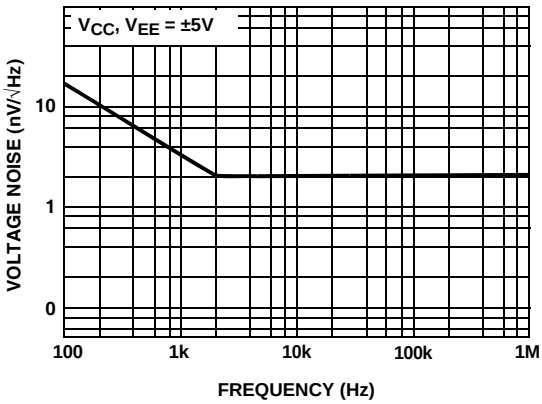


FIGURE 12. VOLTAGE NOISE

Typical Performance Curves (Continued)

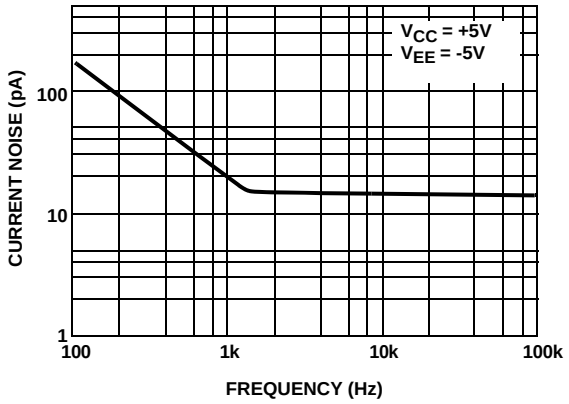


FIGURE 13. CURRENT NOISE

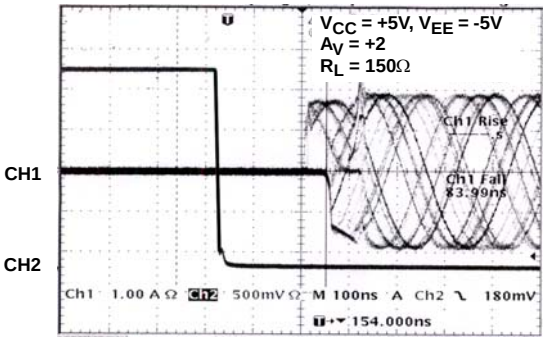


FIGURE 14. TURN-ON DELAY, V_{IN} = 100mV_{P-P}

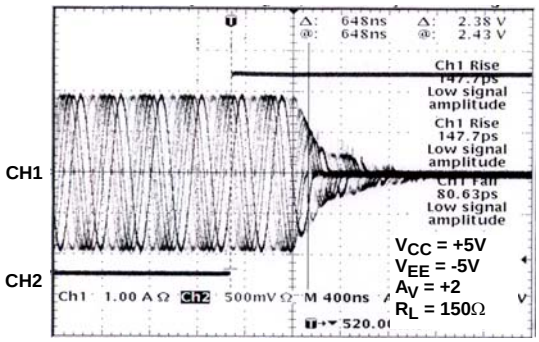


FIGURE 15. TURN-OFF DELAY, V_{IN} = 100mV_{P-P}

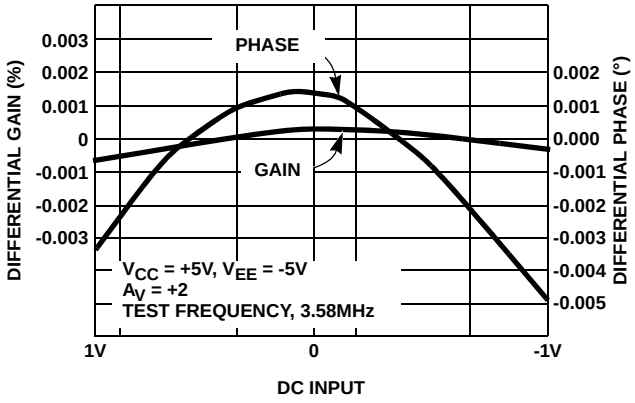


FIGURE 16. DIFFERENTIAL GAIN/PHASE vs DC INPUT VOLTAGE AT 3.58MHz

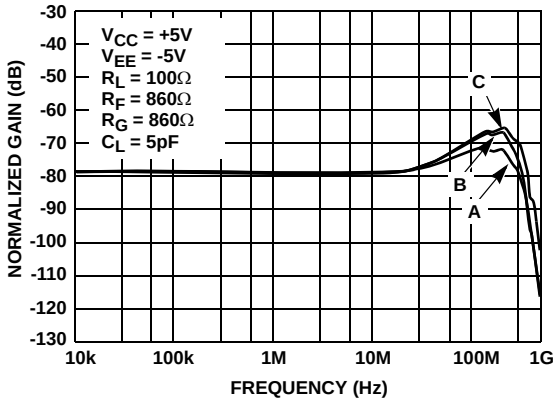


FIGURE 17. FREQUENCY RESPONSE FOR VARIOUS CHANNELS

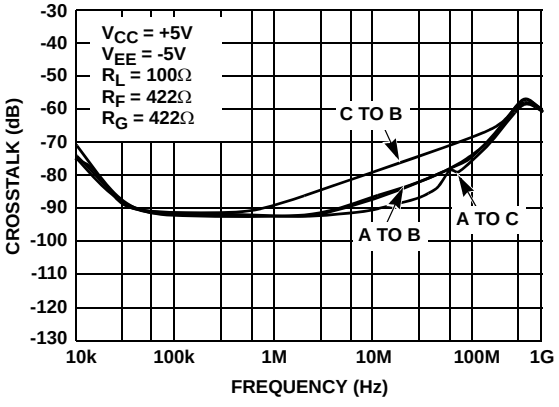


FIGURE 18. CHANNEL CROSSTALK BETWEEN CHANNELS

Typical Performance Curves (Continued)

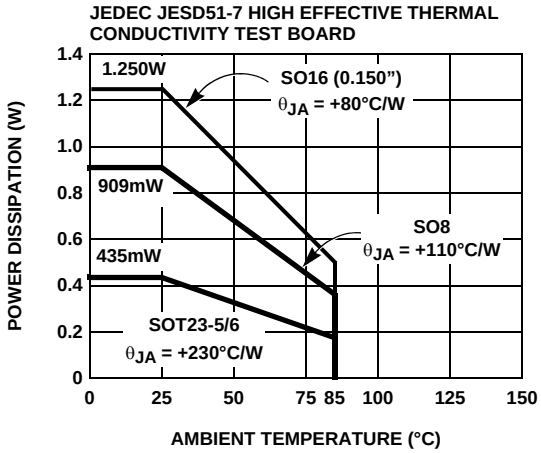


FIGURE 19. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE

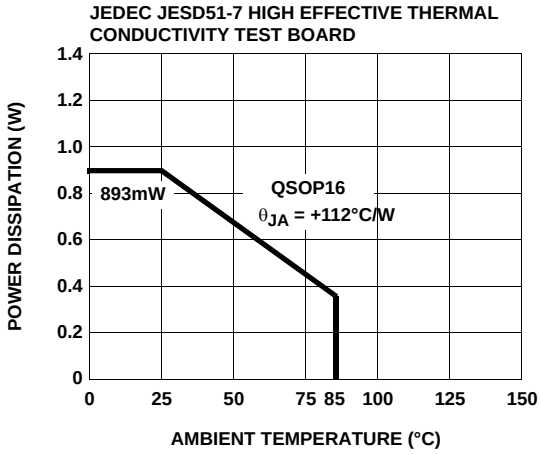


FIGURE 20. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE

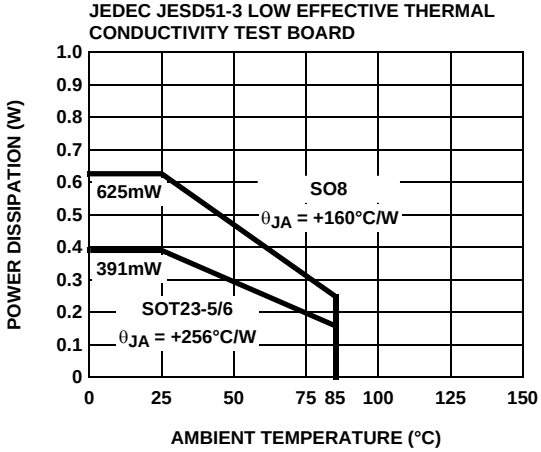


FIGURE 21. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE

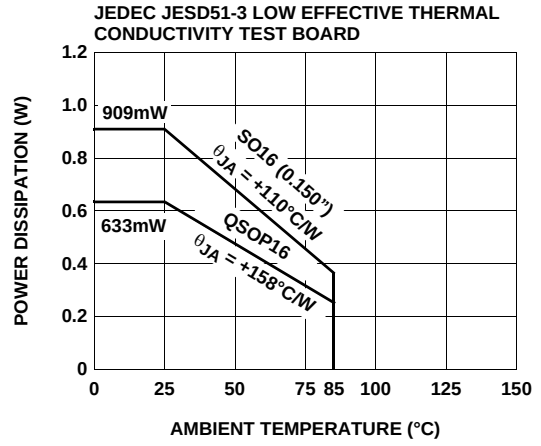
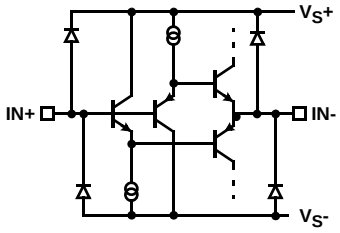
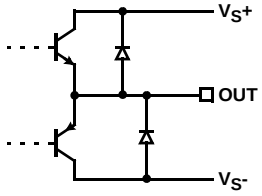
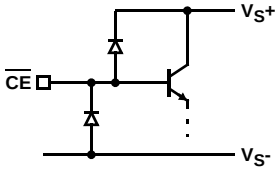


FIGURE 22. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE

Pin Descriptions

EL5164 (8 LD SOIC)	EL5164 (6 LD SOT-23)	EL5165 (5 LD SOT-23)	PIN NAME	FUNCTION	EQUIVALENT CIRCUIT
1, 5			NC	Not connected	
2	4	4	IN-	Inverting input	 CIRCUIT 1
3	3	3	IN+	Non-inverting input	(See circuit 1)
4	2	2	VS-	Negative supply	
6	1	1	OUT	Output	 CIRCUIT 2
7	6	5	VS+	Positive supply	
8	5		$\overline{CE}$	Chip enable, allowing the pin to float or applying a low logic level will enable the amplifier.	 CIRCUIT 3

Applications Information

Product Description

The EL5164, EL5165, and EL5364 are current-feedback operational amplifiers that offers a wide -3dB bandwidth of 600MHz and a low supply current of 5mA per amplifier. The EL5164, EL5165, and EL5364 work with supply voltages ranging from a single 5V to 10V and they are also capable of swinging to within 1V of either supply on the output. Because of their current-feedback topology, the EL5164, EL5165, and EL5364 do not have the normal gain-bandwidth product associated with voltage-feedback operational amplifiers. Instead, its -3dB bandwidth to remain relatively constant as closed-loop gain is increased. This combination of high bandwidth and low power, together with aggressive pricing make the EL5164, EL5165, and EL5364 ideal choices for many low-power/high-bandwidth applications such as portable, handheld, or battery-powered equipment.

For varying bandwidth needs, consider the EL5166 and EL5167 with 1GHz on a 8.5mA supply current or the EL5162 and EL5163 with 300MHz on a 1.5mA supply current. Versions include single, dual, and triple amp packages with 5 Ld SOT-23, 16 Ld QSOP, and 8 Ld SOIC or 16 Ld SOIC outlines.

Power Supply Bypassing and Printed Circuit Board Layout

As with any high frequency device, good printed circuit board layout is necessary for optimum performance. Low impedance ground plane construction is essential. Surface mount components are recommended, but if leaded components are used, lead lengths should be as short as possible. The power supply pins must be well bypassed to reduce the risk of oscillation. The combination of a 4.7µF tantalum capacitor in parallel with a 0.01µF capacitor has been shown to work well when placed at each supply pin.

For good AC performance, parasitic capacitance should be kept to a minimum, especially at the inverting input. (See the “Capacitance at the Inverting Input” on page 10). Even when ground plane construction is used, it should be removed from the area near the inverting input to minimize any stray capacitance at that node. Carbon or Metal-Film resistors are acceptable with the Metal-Film resistors giving slightly less peaking and bandwidth because of additional series

inductance. Use of sockets, particularly for the SO package, should be avoided if possible. Sockets add parasitic inductance and capacitance which will result in additional peaking and overshoot.

Disable/Power-Down

The EL5164 amplifier can be disabled placing its output in a high impedance state. When disabled, the amplifier supply current is reduced to <150µA. The EL5164 is disabled when its $\overline{CE}$ pin is pulled up to within 1V of the positive supply. Similarly, the amplifier is enabled by floating or pulling its $\overline{CE}$ pin to at least 3V below the positive supply. For ±5V supply, this means that an EL5164 amplifier will be enabled when $\overline{CE}$ is 2V or less, and disabled when $\overline{CE}$ is above 4V. Although the logic levels are not standard TTL, this choice of logic voltages allows the EL5164 to be enabled by tying $\overline{CE}$ to ground, even in 5V single supply applications. The $\overline{CE}$ pin can be driven from CMOS outputs.

When the amplifier is disabled, if the positive input is driven beyond ±2V with respect to the negative input, the device can become active and output the signal. An input diode clamp network D_1 and D_2, as shown in Figure 23, can be used to keep the device disabled while a large input signal is present.

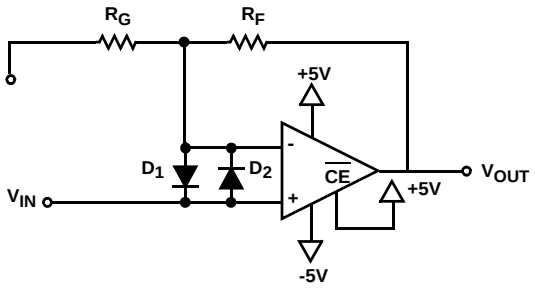


FIGURE 23. DISABLED AMPLIFIER

Capacitance at the Inverting Input

Any manufacturer's high-speed voltage- or current-feedback amplifier can be affected by stray capacitance at the inverting input. For inverting gains, this parasitic capacitance has little effect because the inverting input is a virtual ground, but for non-inverting gains, this capacitance (in conjunction with the feedback and gain resistors) creates a pole in the feedback path of the amplifier. This pole, if low enough in frequency, has the same destabilizing effect as a zero in the forward open-loop response. The use of large-value feedback and gain resistors exacerbates the problem by further lowering the pole frequency (increasing the possibility of oscillation.)

The EL5164, EL5165, and EL5364 have been optimized with a 510Ω feedback resistor. With the high bandwidth of these amplifiers, these resistor values might cause stability problems when combined with parasitic capacitance, thus ground plane is not recommended around the inverting input pin of the amplifier.

Feedback Resistor Values

The EL5164, EL5165, and EL5364 have been designed and specified at a gain of +2 with R_F approximately 412Ω. This value of feedback resistor gives 300MHz of -3dB bandwidth at A_V = 2 with 2dB of peaking. With A_V = -2, an R_F of 300Ω gives 275MHz of bandwidth with 1dB of peaking. Since the EL5164, EL5165, and EL5364 are current-feedback amplifiers, it is also possible to change the value of R_F to get more bandwidth. As seen in the curve of Frequency Response for Various R_F and R_G, bandwidth and peaking can be easily modified by varying the value of the feedback resistor.

Because the EL5164, EL5165, and EL5364 are current-feedback amplifiers, their gain-bandwidth product is not a constant for different closed-loop gains. This feature actually allows the EL5164, EL5165, and EL5364 to maintain about the same -3dB bandwidth. As gain is increased, bandwidth decreases slightly while stability increases. Since the loop stability is improving with higher closed-loop gains, it becomes possible to reduce the value of R_F below the specified 160Ω and still retain stability, resulting in only a slight loss of bandwidth with increased closed-loop gain.

Supply Voltage Range and Single-Supply Operation

The EL5164, EL5165, and EL5364 have been designed to operate with supply voltages having a span of greater than 5V and less than 10V. In practical terms, this means that they will operate on dual supplies ranging from ±2.5V to ±5V. With single-supply, the EL5164, EL5165, and EL5364 will operate from 5V to 10V.

As supply voltages continue to decrease, it becomes necessary to provide input and output voltage ranges that can get as close as possible to the supply voltages. The EL5164, EL5165, and EL5364 have an input range which extends to within 2V of either supply. So, for example, on ±5V supplies, the EL5164, EL5165, and EL5364 have an input range which spans ±3V. The output range of the EL5164, EL5165, and EL5364 is also quite large, extending to within 1V of the supply rail. On a ±5V supply, the output is therefore capable of swinging from -4V to +4V. Single-supply output range is larger because of the increased negative swing due to the external pull-down resistor to ground.

Video Performance

For good video performance, an amplifier is required to maintain the same output impedance and the same frequency response as DC levels are changed at the output. This is especially difficult when driving a standard video load of 150Ω, because of the change in output current with DC level. Previously, good differential gain could only be achieved by running high idle currents through the output transistors (to reduce variations in output impedance.) These currents were typically comparable to the entire 5.5mA supply current of

each EL5164, EL5165, and EL5364 amplifiers. Special circuitry has been incorporated in the EL5164, EL5165, and EL5364 to reduce the variation of output impedance with current output. This results in dG and dP specifications of 0.01% and 0.01°, while driving 150Ω at a gain of 2.

Video performance has also been measured with a 500Ω load at a gain of +1. Under these conditions, the EL5164, EL5165, and EL5364 have dG and dP specifications of 0.01% and 0.01°, respectively.

Output Drive Capability

In spite of their low 5.5mA of supply current, the EL5164, EL5165, and EL5364 are capable of providing a minimum of ±75mA of output current. With a minimum of ±75mA of output drive, the EL5164, EL5165, and EL5364 are capable of driving 50Ω loads to both rails, making it an excellent choice for driving isolation transformers in telecommunications applications.

Driving Cables and Capacitive Loads

When used as a cable driver, double termination is always recommended for reflection-free performance. For those applications, the back-termination series resistor will decouple the EL5164, EL5165, and EL5364 from the cable and allow extensive capacitive drive. However, other applications may have high capacitive loads without a back-termination resistor. In these applications, a small series resistor (usually between 5Ω and 50Ω) can be placed in series with the output to eliminate most peaking. The gain resistor (R_G) can then be chosen to make up for any gain loss which may be created by this additional resistor at the output. In many cases it is also possible to simply increase the value of the feedback resistor (R_F) to reduce the peaking.

Current Limiting

The EL5164, EL5165, and EL5364 have no internal current-limiting circuitry. If the output is shorted, it is possible to exceed the Absolute Maximum Rating for output current or power dissipation, potentially resulting in the destruction of the device.

Power Dissipation

With the high output drive capability of the EL5164, EL5165, and EL5364, it is possible to exceed the +125°C Absolute Maximum junction temperature under certain very high load current conditions. Generally speaking when R_L falls below about 25Ω, it is important to calculate the maximum junction temperature (T_{JMAX}) for the application to determine if power supply voltages, load conditions, or package type need to be modified for the EL5164, EL5165, and EL5364 to remain in the safe operating area. These parameters are calculated in Equation 1:

$$T_{JMAX} = T_{MAX} + (\theta_{JA} \times n \times PD_{MAX}) \quad \text{(EQ. 1)}$$

where:

- T_{MAX} = Maximum ambient temperature
- θ_{JA} = Thermal resistance of the package
- n = Number of amplifiers in the package
- PD_{MAX} = Maximum power dissipation of each amplifier in the package

PD_{MAX} for each amplifier can be calculated in Equation 2:

$$PD_{MAX} = (2 \times V_S \times I_{SMAX}) + \left[(V_S - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_L}\right] \quad \text{(EQ. 2)}$$

where:

- V_S = Supply voltage
- I_{SMAX} = Maximum supply current of 1A
- V_{OUTMAX} = Maximum output voltage (required)
- R_L = Load resistance

Typical Application Circuits

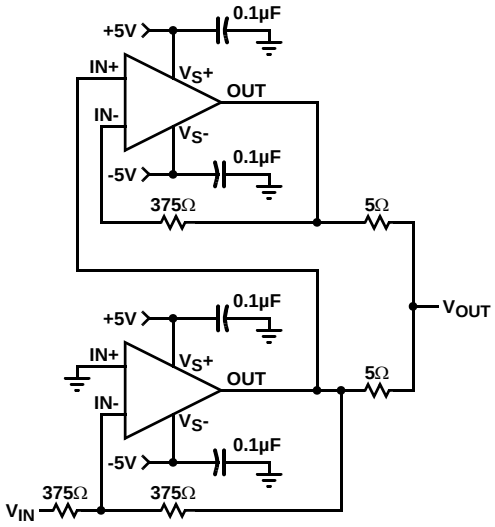


FIGURE 24. INVERTING 200mA OUTPUT CURRENT DISTRIBUTION AMPLIFIER

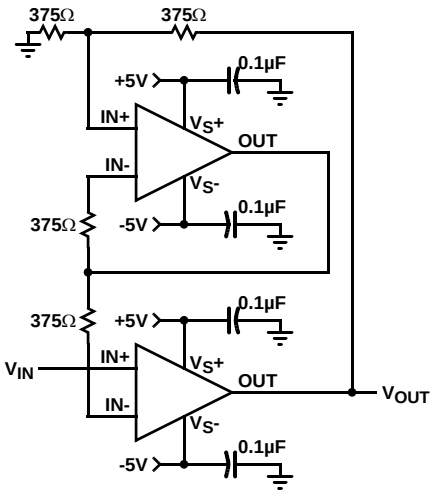


FIGURE 25. FAST-SETTLING PRECISION AMPLIFIER

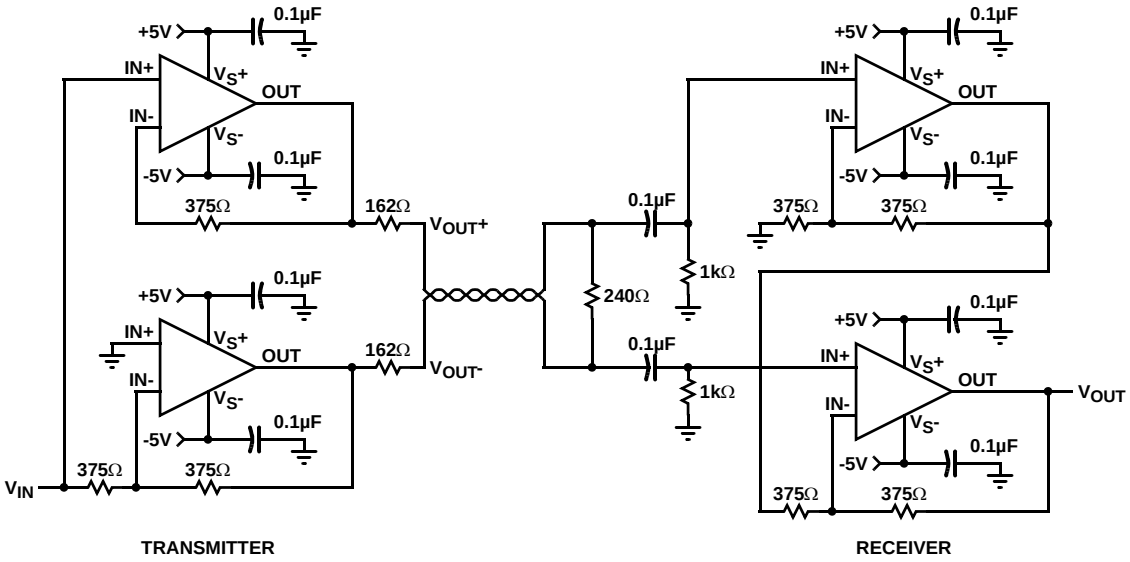
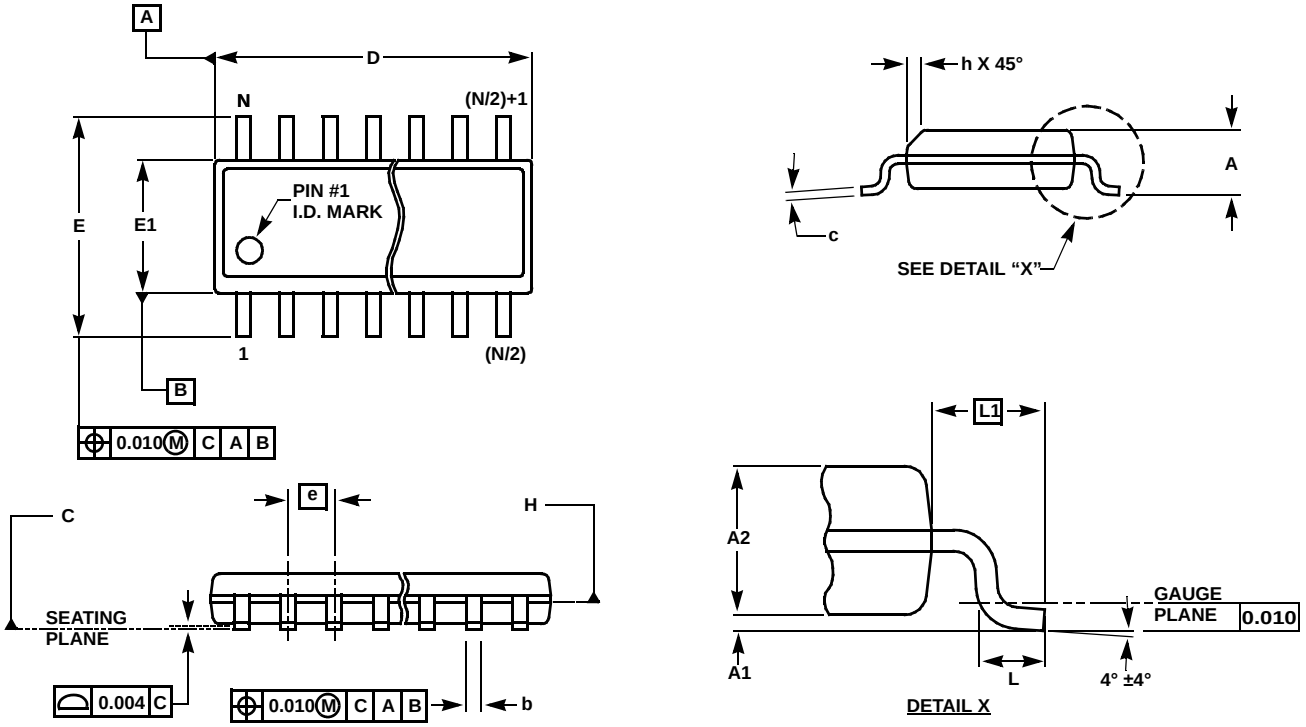


FIGURE 26. DIFFERENTIAL LINE DRIVER/RECEIVER

Small Outline Package Family (SO)



MDP0027

SMALL OUTLINE PACKAGE FAMILY (SO)

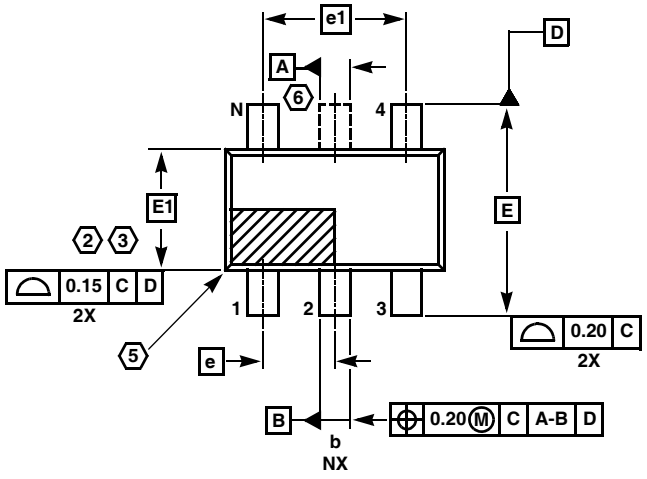
SYMBOL	INCHES							TOLERANCE	NOTES
	SO-8	SO-14	SO16 (0.150")	SO16 (0.300") (SOL-16)	SO20 (SOL-20)	SO24 (SOL-24)	SO28 (SOL-28)		
A	0.068	0.068	0.068	0.104	0.104	0.104	0.104	MAX	-
A1	0.006	0.006	0.006	0.007	0.007	0.007	0.007	±0.003	-
A2	0.057	0.057	0.057	0.092	0.092	0.092	0.092	±0.002	-
b	0.017	0.017	0.017	0.017	0.017	0.017	0.017	±0.003	-
c	0.009	0.009	0.009	0.011	0.011	0.011	0.011	±0.001	-
D	0.193	0.341	0.390	0.406	0.504	0.606	0.704	±0.004	1, 3
E	0.236	0.236	0.236	0.406	0.406	0.406	0.406	±0.008	-
E1	0.154	0.154	0.154	0.295	0.295	0.295	0.295	±0.004	2, 3
e	0.050	0.050	0.050	0.050	0.050	0.050	0.050	Basic	-
L	0.025	0.025	0.025	0.030	0.030	0.030	0.030	±0.009	-
L1	0.041	0.041	0.041	0.056	0.056	0.056	0.056	Basic	-
h	0.013	0.013	0.013	0.020	0.020	0.020	0.020	Reference	-
N	8	14	16	16	20	24	28	Reference	-

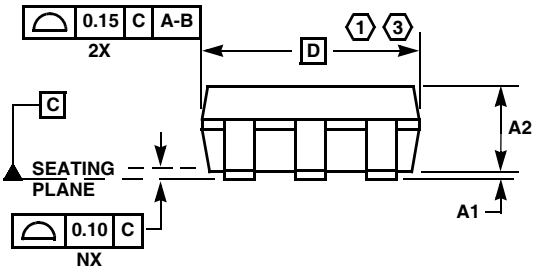
Rev. M 2/07

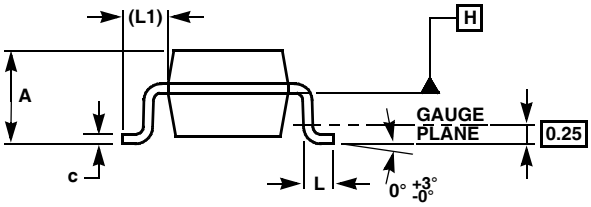
NOTES:

1. Plastic or metal protrusions of 0.006" maximum per side are not included.
2. Plastic interlead protrusions of 0.010" maximum per side are not included.
3. Dimensions "D" and "E1" are measured at Datum Plane "H".
4. Dimensioning and tolerancing per ASME Y14.5M-1994

SOT-23 Package Family







MDP0038

SOT-23 PACKAGE FAMILY

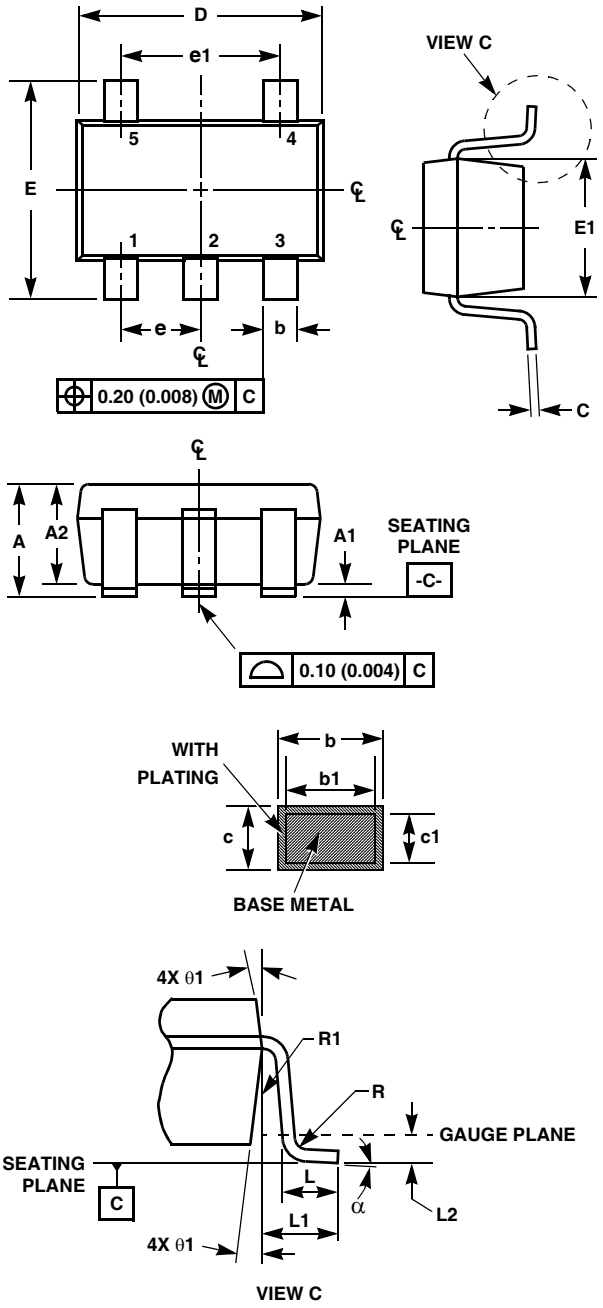
SYMBOL	MILLIMETERS		TOLERANCE
	SOT23-5	SOT23-6	
A	1.45	1.45	MAX
A1	0.10	0.10	±0.05
A2	1.14	1.14	±0.15
b	0.40	0.40	±0.05
c	0.14	0.14	±0.06
D	2.90	2.90	Basic
E	2.80	2.80	Basic
E1	1.60	1.60	Basic
e	0.95	0.95	Basic
e1	1.90	1.90	Basic
L	0.45	0.45	±0.10
L1	0.60	0.60	Reference
N	5	6	Reference

Rev. F 2/07

NOTES:

1. Plastic or metal protrusions of 0.25mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25mm maximum per side are not included.
3. This dimension is measured at Datum Plane “H”.
4. Dimensioning and tolerancing per ASME Y14.5M-1994.
5. Index area - Pin #1 I.D. will be located within the indicated zone (SOT23-6 only).
6. SOT23-5 version has no center lead (shown as a dashed line).

Small Outline Transistor Plastic Packages (SC70-5)



P5.049

5 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE

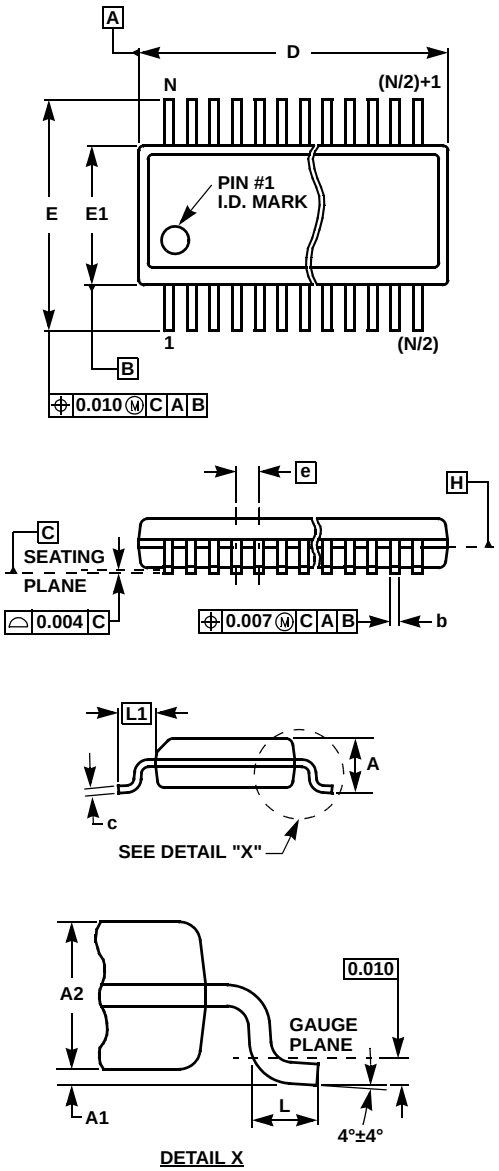
SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.031	0.043	0.80	1.10	-
A1	0.000	0.004	0.00	0.10	-
A2	0.031	0.039	0.80	1.00	-
b	0.006	0.012	0.15	0.30	-
b1	0.006	0.010	0.15	0.25	
c	0.003	0.009	0.08	0.22	6
c1	0.003	0.009	0.08	0.20	6
D	0.073	0.085	1.85	2.15	3
E	0.071	0.094	1.80	2.40	-
E1	0.045	0.053	1.15	1.35	3
e	0.0256 Ref		0.65 Ref		-
e1	0.0512 Ref		1.30 Ref		-
L	0.010	0.018	0.26	0.46	4
L1	0.017 Ref.		0.420 Ref.		-
L2	0.006 BSC		0.15 BSC		
α	0^o	8^o	0^o	8^o	-
N	5		5		5
R	0.004	-	0.10	-	
R1	0.004	0.010	0.15	0.25	

Rev. 2 9/03

NOTES:

1. Dimensioning and tolerances per ASME Y14.5M-1994.
2. Package conforms to EIAJ SC70 and JEDEC MO-203AA.
3. Dimensions D and E1 are exclusive of mold flash, protrusions, or gate burrs.
4. Footlength L measured at reference to gauge plane.
5. “N” is the number of terminal positions.
6. These Dimensions apply to the flat section of the lead between 0.08mm and 0.15mm from the lead tip.
7. Controlling dimension: MILLIMETER. Converted inch dimensions are for reference only.

Quarter Size Outline Plastic Packages Family (QSOP)



MDP0040

QUARTER SIZE OUTLINE PLASTIC PACKAGES FAMILY

SYMBOL	INCHES			TOLERANCE	NOTES
	QSOP16	QSOP24	QSOP28		
A	0.068	0.068	0.068	Max.	-
A1	0.006	0.006	0.006	±0.002	-
A2	0.056	0.056	0.056	±0.004	-
b	0.010	0.010	0.010	±0.002	-
c	0.008	0.008	0.008	±0.001	-
D	0.193	0.341	0.390	±0.004	1, 3
E	0.236	0.236	0.236	±0.008	-
E1	0.154	0.154	0.154	±0.004	2, 3
e	0.025	0.025	0.025	Basic	-
L	0.025	0.025	0.025	±0.009	-
L1	0.041	0.041	0.041	Basic	-
N	16	24	28	Reference	-

Rev. F 2/07

NOTES:

1. Plastic or metal protrusions of 0.006” maximum per side are not included.
2. Plastic interlead protrusions of 0.010” maximum per side are not included.
3. Dimensions “D” and “E1” are measured at Datum Plane “H”.
4. Dimensioning and tolerancing per ASME Y14.5M-1994.

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